

4N29, 4N30, 4N31, 4N32, 4N33



ISOCOM
COMPONENTS

**OPTICALLY COUPLED ISOLATOR
PHOTODARLINGTON OUTPUT**



DESCRIPTION

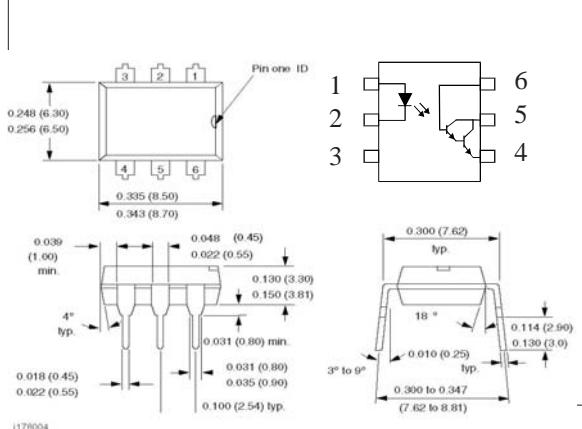
The 4N29, 4N30, 4N31, 4N32, 4N33 series of optically coupled isolators consist of an infrared light emitting diode and NPN silicon photodarlington in a space efficient dual in line plastic package.

FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature _____ -55°C to + 150°C
Operating Temperature _____ -55°C to + 100°C
Lead Soldering Temperature
(1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

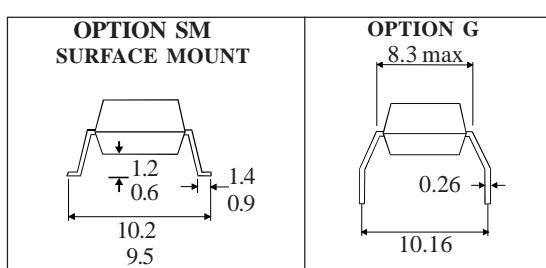
Forward Current _____ 80mA
Reverse Voltage _____ 5V
Power Dissipation _____ 100mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO} _____ 30V
Collector-base Voltage BV_{CBO} _____ 50V
Emitter-collector Voltage BV_{ECO} _____ 5V
Power Dissipation _____ 150mW

POWER DISSIPATION

Total Power Dissipation _____ 250mW
(derate linearly 3.3mW/°C above 25°C)



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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	$I_F = 50\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 6\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) Collector-base Breakdown (BV_{CBO}) Emitter-collector Breakdown (BV_{ECO}) Collector-emitter Dark Current (I_{CEO})	30 50 5		100	V V V nA	$I_C = 1\text{mA}$ (note 2) $I_C = 100\mu\text{A}$ $I_E = 100\mu\text{A}$ $V_{CE} = 10\text{V}$
Coupled	Collector Output Current (I_C) (Note 2) 4N32, 4N33 4N29, 4N30 4N31	50 10 5			mA mA mA	$10\text{mA } I_F, 10\text{V } V_{CE}$ $10\text{mA } I_F, 10\text{V } V_{CE}$ $10\text{mA } I_F, 10\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$ 4N29, 4N30, 4N32, 4N33 4N31			1.0 1.2	V V	$8\text{mA } I_F, 2\text{mA } I_C$ $8\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	(note 1) (note 1)
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Output Turn on Time t_{on} Output Turn off Time t_{off} 4N32, 4N33 4N29, 4N30, 4N31			5 100 40	μs μs μs	$V_{CC} = 10\text{V}, I_C = 50\text{mA},$ $I_F = 200\text{mA},$ Pulse Width = 1ms fig.1

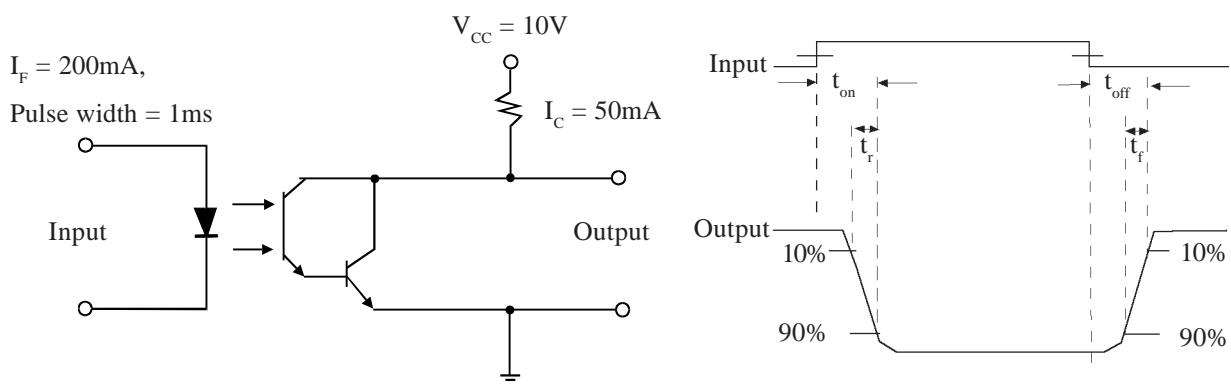
Note 1

Measured with input leads shorted together and output leads shorted together.

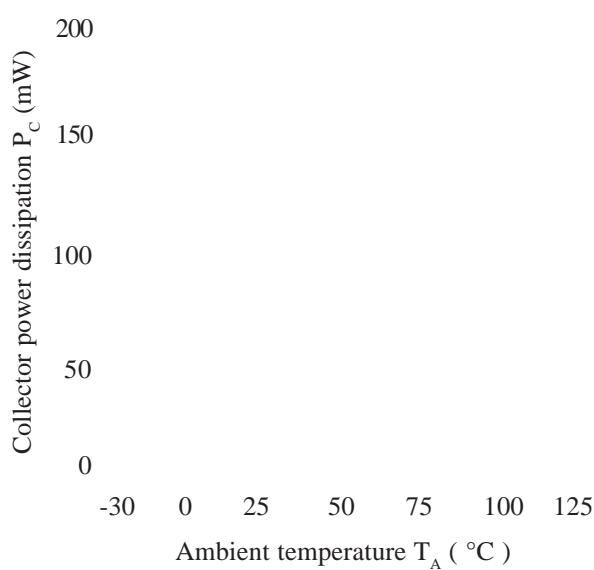
Note 2

Special Selections are available on request. Please consult the factory.

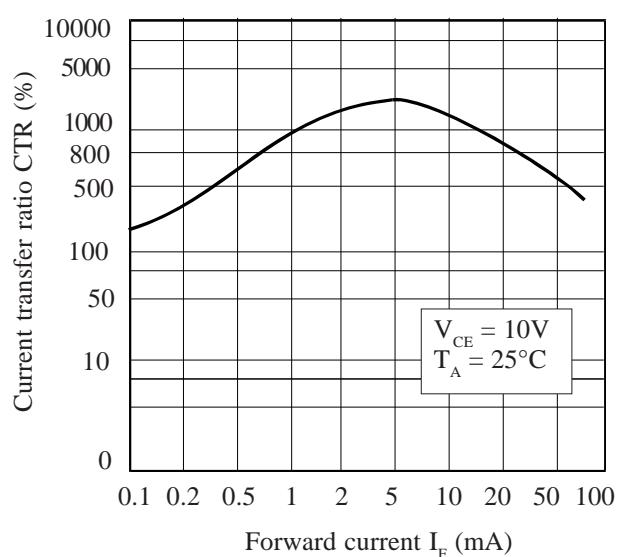
FIGURE 1



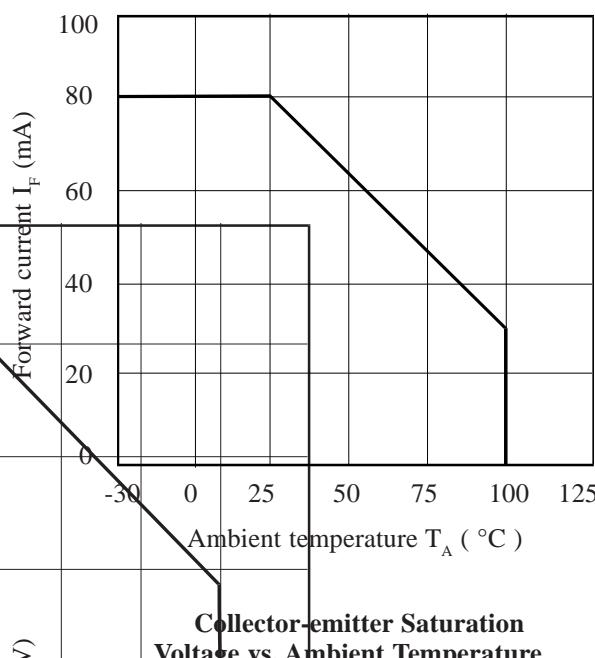
Collector Power Dissipation vs. Ambient Temperature



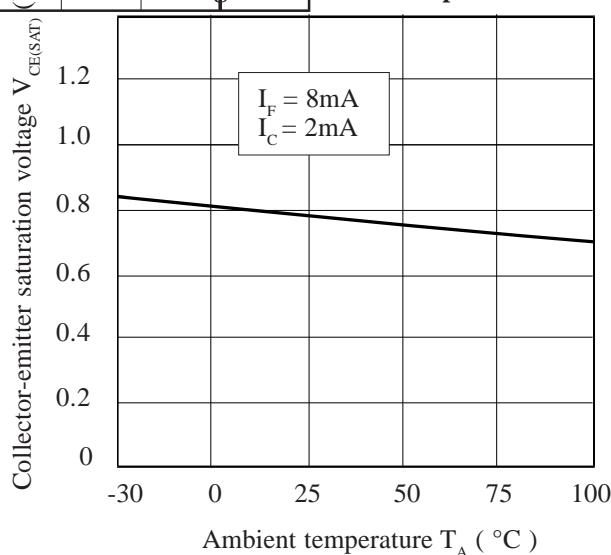
Current Transfer Ratio vs. Forward Current



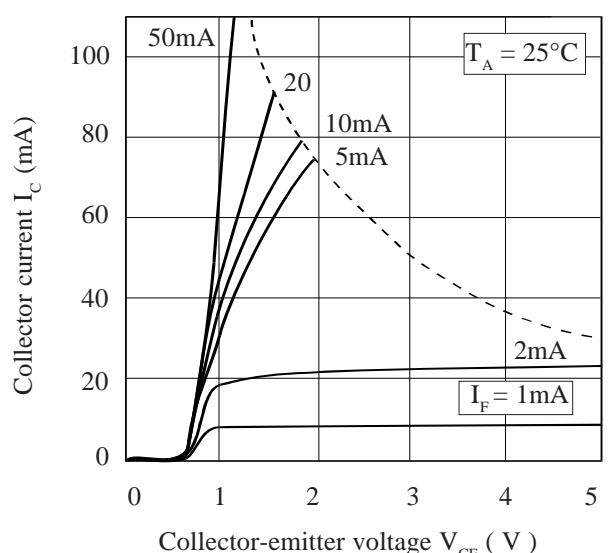
Forward Current vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature



Collector Current vs. Collector-emitter Voltage



Relative Current Transfer Ratio vs. Ambient Temperature

